SCHEMATIC SYMBOL	DESCRIPTION	B&K PART No.			
SWITCHES					
S105 S106, VR109, VR110 S101, S103, S107, S108 S109	Rotary Switch (MODE)	3-137-9-003 4-022-9-001			
	MISCELLANEOUS				
	Bezel       380         Bezel Retaining Nut       653         Case       272         Fuse, 1 Amp, 3 AG       19         Graticule       380         Graticule Filter, Green       380         Knob, (VOLTS/CM, SWEEP TIME, MO       Grey         Knob, Grey       75         Knob, Grey       75         Knob, (STABILITY), Grey       75         Knob, Black       75         Knob, (V POSITION), Grey       75         Knob, (V POSITION), Grey       75	3-011-9-001 2-082-9-001 1-251-3-001 0-137-9-002 0-137-9-003 DE) 1-077-9-001 1-077-9-003 1-077-9-004 1-091-9-001			
PL101, PL102	Lamp, Scale Illumination				
NOTE: Standard Value resistors are not listed. Values may be obtained from the Schematic Diagram.					

SPECIFY SERIAL NO. WHEN ORDERING REPLACEMENT PARTS

## B & K MODEL 1470 PARTS LIST

488-119-9-002

## HORIZONTAL AMP/SWEEP P.C. BOARD

SCHEMATIC SYMBOL	DESCRIPTION	B & K PART No.
	RESISTORS & CONTROLS	
R46	22KΩ, 2W, 5%, Metal Film Resistor011	-002-5-223
R49	22KΩ, 3W, 5%, Metal Film Resistor011	-003-5-223
R57, R58	15KΩ, 2W, 5%, Metal Film Resistor011	-002-5-153
R62	680Ω, 2W, 5%, Metal Film Resistor011	-002-5-681
R67	470 $\Omega$ , 3W, 5% Metal Film Resistor011	-003-5-471
VR1	2.2KΩ, 0.15W, 25%, Trim Pot008	3-169-9-007
VR2, VR3, VR10	47KΩ, 0.15W, 25%, Trim Pot008	3-169-9-008
VR4, VR5	10KΩ, 0.15W, 25%, Trim Pot008	3-155-9-004
VR6, VR7	1KΩ, 0.15W, 25%, Trim Pot008	3-155-9-005
VR8	330Ω, 0.15W, 25%, Trim Pot008	3-155-9-006
VR9	22KΩ, 0.15W, 25%, Trim Pot008	3-163-9-010
	CAPACITORS	
C2	1μfd, 50V, Non-Polarlytic034	1-003-9-002
C10, C11	10μfd, 25V, Electrolytic Capacitor022	2-086-9-005
C14	100μfd, 16V, Electrolytic Capacitor022	2-073-9-002
C27, C31	470μfd, 16V, Electrolytic Capacitor022	2-073-9-003
C28	100 µfd, 50V, Electrolytic Capacitor022	2-073-9-007
C29, C30, C32	220μfd, 50V, Electrolytic Capacitor022	2-073-9-006
	DIODES & TRANSISTORS	
D1, D3, D4-D6	Diode, Silicon, 1S1555	l- <b>028-9</b> -007
D2	Diode, Silicon 1N60150	0-001-9-005
D7, D10	Zener Diode, ZB1-6152	2-041-9-001
D8	Diode, Silicon, 1S185015	1-028-9-002
<b>D</b> 9	Diode, Silicon, 1S1850R	1-028-9-003
D11	Diode, Silicon, 10D1015	1-028-9-006
Q1-Q4, Q6-Q11		
Q16, Q17, Q21, Q22	Transistor, Silicon, NPN, 2SC458-C17	6-016-9-001
Q5, Q14	Transistor, Field Effect, 2SK19-G (IGSS)18	2-021-9-001
Q12, Q18, Q19	Transistor, Silicon, NPN, 2SC1012-A17	6-028-9-008
Q13	Transistor, Field Effect, 2SK19-Y (IGSS)18	2-021-9-002
Q15	Transistor, Silicon, NPN, 2SC98417	6-034-9-001
Q20	Transistor, Silicon, NPN, 2SC97117	6-028-9-007

SCHEMATIC SYMBOL	DESCRIPTION	B&K Part No	SCHEMATIC SYMBOL	- <del></del>	B&K PART No.
CH1 & CH 2 VERTICAL AMPLIFIER P.C. BOARD		S-102/VR102 S-104/VR105	"VOLTS/CM" Switch & Variable Control (CH1 & CH2)	083-137-9-001	
RESISTORS & CONTROLS		R101, R107	900KΩ, ½W, 1%, Deposited Carbon	000 100 0 001	

CHI & CH 2	VERTICAL AMPLIFIER P.C. BUARD	S-102/VR102 S-104/VR105	"VOLTS/CM" Switch & Variable Control (CH1 & CH2)083-137-9-001
R53, R54	RESISTORS & CONTROLS $8K\Omega$ , $1W$ , $5\%$ , Metal Film Resistor011-001-5-802	R101, R107	900KΩ, ½W, 1%, Deposited Carbon Resistor002-102-3-904
R60, R61	$2.7K\Omega$ , 3W, 5%, Metal Film Resistor011-003-5-272	R102, R108	111KΩ, ½W, 1%, Deposited Carbon Resistor002-001-9-021
VR1, VR5 VR2, VR6	68KΩ, 0.15W, 25%, Trim Pot008-169-9-009 22KΩ, 0.15W, 25%, Trim Pot008-163-9-010	R103, R109	990KΩ, ½W, 1%, Deposited Carbon Resistor
VR3-VR7	10KΩ, 0.15W, 25%, Trim Pot008-155-9-004	R104, R110	10.1KΩ, ½W, 1%, Deposited Carbon Resistor
VR4 VR8	150Ω, 0.15W, 25%, Trim Pot008-174-9-002 330Ω, 0.15W, 25%, Trim Pot008-155-9-006	R105, R111	999KΩ, ½W, 1%, Deposited Carbon
	CAPACITORS & TRIMMERS	R106, R112	Resistor       .002-001-9-028         1KΩ, ½W, 1%, Deposited Carbon       .002-102-3-102         Resistor
C2, C3, C7, C8 C11	100μfd, 16V, Electrolytic Capacitor022-073-9-002 47μfd, 50V, Electrolytic Capacitor022-087-9-002	R116, R117	1MΩ, ½W, 1%, Deposited Carbon Resistor
C15, C25	$22\mu\mathrm{fd}$ , 50V, Electrolytic Capacitor022-090-9-002		MAIN CHASSIS
C16	22μfd, 250V, Electrolytic Capacitor021-038-9-002		RESISTORS & CONTROLS
C17, C18	47μfd, 16V, Electrolytic Capacitor022-090-9-003	VR101, VR103	5KΩ, Carbon Pot, "DC BAL"008-174-9-003
TC1, TC3	10pfd, Trimmer Capacitor028-020-9-003	VR-104, VR106	5KΩ, Carbon Pot, "V POS"008-174-9-003
TC2, TC4	20pfd, Trimmer Capacitor028-020-9-002	VR107	100KΩ, Carbon Pot, "TRIG LEVEL"008-174-9-001
TC5, TC6	70pfd, Trimmer Capacitor028-025-9-002	VR108	100KΩ, Carbon Pot, "STABILITY"008-174-9-001
	COILS & CHOKES	VR112	250KΩ, 0.2W, 20%, Carbon Pot, "ASTIG"008-169-9-003
L1, L2	20μH, Peaking Coil	VR113	1MΩ, 0.25W, 20%, Carbon Pot, "INTENSITY"008-163-9-003
D. D.	DIODES & TRANSISTORS	VR114	500KΩ, 0.25W, 20%, Carbon Pot,
D1,-D10	Diode, Silicon, 1S1555		"FOCUS"008-169-9-004
D11, D12	Diode, Germanium, 1N60150-001-9-005	VR115/S112	100Ω, 0.25W, 20%, Carbon Pot,
Q1, Q10	Transistor, Field Effect, 2SK19-GR (IGSS)182-021-9-001		"ILLUM"
Q2-Q5,	Transistor, Field Effect, 2SK30-O182-014-9-003	C126	0.5 ufd x 5, 1.5 KV, 5 Section Oil
Q11-Q14			Capacitor
Q6, Q7, Q15, Q16, Q19,		C127	47ufd, 250V, 3 Section Electrolytic Capacitor
Q22, Q23, / \\ Q30, Q33, \\ Q36, Q39	Transistor, Silicon, NPN, 2SC458-C176-016-9-001	TC101, TC103, TC105, TC107, TC109, TC111	50 pfd, Trimmer Capacitor
Q8, Q9, Q17, Q18, Q20, Q21, Q28, Q29	Transistor, Silicon, NPN, 2SC535-B176-036-9-001	TC102, TC104, TC106, TC108, TC110,TC112 TC113, TC114	10pfd, Trimmer Capacitor028-020-9-004
Q24, Q25	Transistor Silicon, NPN, 2SC284-H176-028-9-005	n	DIODES, TRANSISTORS & TUBES
Q26, Q27	Transistor, Silicon, NPN, 2SC996176-028-9-006	D101, D102	Diode, Silicon ED01-04151-033-9-001
Q34, Q35	Transistor, Silicon, PNP, 2SA562-Y177-006-9-002	D103, D104	Diode, Silicon S-05-08151-033-9-002
Q40	Transistor Silicon, NPN, 2SC1012-A176-028-9-008		CRT 5DEPI (S)230-003-9-001

